



SUPER BARRIER RECTIFIER

Product Summary

	V _{RRM} (V)	I _O (A)	V _F Max (V) @ +25°C	I _R Max (mA) +25°C
ı	60	2	0.51	0.15

Description and Applications

The SBR2U60S1FQ is a single rectifier packaged in SOD123F. Offering low V_F , low power loss and high efficiency, this device is ideal for use in general rectification applications as a:

- Boost Diode
- Blocking Diode

Features and Benefits

- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- Patented Interlocking Clip Design for High Surge Current Capacity
- Patented Super Barrier Rectifier SBR[®] Technology
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOD123F
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 @3
- Polarity: Cathode Band
- Weight: 0.015 grams (Approximate)

SOD123F



Top View

Ordering Information (Note 5)

г			
	Part Number	Case	Packaging
	SBR2U60S1FQ-7	SOD123F	3,000/Tape & Reel

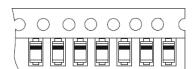
Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



H6 = Product Type Marking Code
YM = Date Code Marking
Y = Year (ex: D = 2016)
M = Month (ex: 9 = September)
Bar Denotes Cathode Pin



Date Code Key

Year	2013	2014	2015	2016	2017	2018	2019	2020
Code	Α	В	С	D	Е	F	G	H

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	60	>
Average Rectified Output Current	lo	2	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	35	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Case (Note 6) Typical Thermal Resistance Junction to Ambient (Note 6)	R _{ØJC} R _{ØJA}	30 88	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +175	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

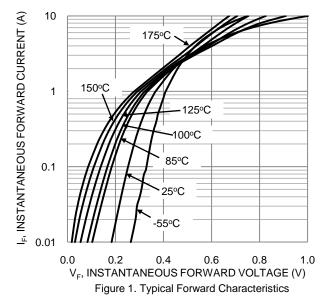
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 7)	$V_{(BR)R}$	60	_		V	$I_R = 1.0 \text{mA}$
		_	0.37	0.46		$I_F = 1A, T_J = +25^{\circ}C$
Forward Voltage Drop	VF	_	0.44	0.51	V	$I_F = 2A, T_J = +25^{\circ}C$
		_	0.42			$I_F = 2A$, $T_J = +125$ °C
		_	20	_	μА	$V_R = 10V, T_J = +25^{\circ}C$
Leakage Current (Note 7)	I _R	_	50	150	μΑ	$V_R = 60V, T_J = +25$ °C
		_	6.5	1	mA	$V_R = 60V, T_J = +125$ °C
Total Capacitance	Ст	_	75	_	pF	$V_R = 10V$, $f = 1MHz$

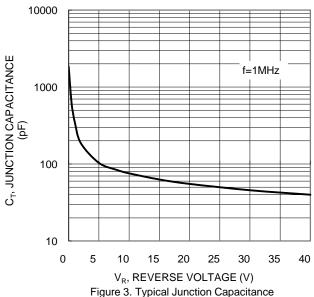
Notes:

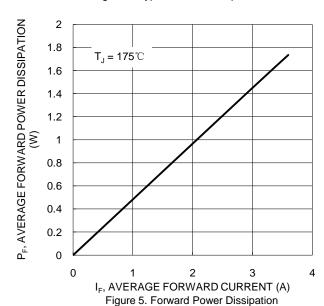
^{6.} Device mounted on FR-4 substrate, 1.0"*1.0", 2oz, single-sided, PC boards with 0.2"*0.25" copper pad. 7. Short duration pulse test used to minimize self-heating effect.

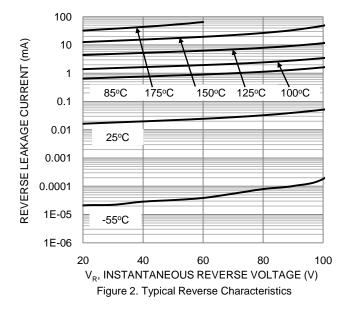


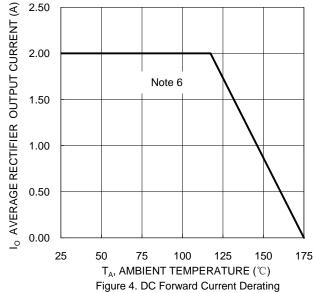












April 2016

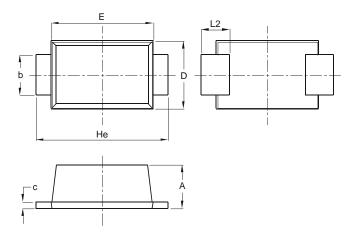
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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOD123F

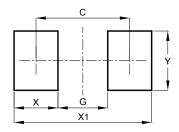


SOD123F									
Dim	Min	Max	Тур						
Α	0.81	1.15	-						
b	0.80	1.35	-						
С	0.05	0.30	-						
D	1.70	1.90	1.80						
Е	2.60	2.80	2.70						
He	3.30	3.70	3.50						
L2	0.35	0.85	-						
All D	imens	ions ir	mm r						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOD123F



Dimensions	Value (in mm)
С	2.86
G	1.52
Х	1.34
X1	4.20
Υ	1.80



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